

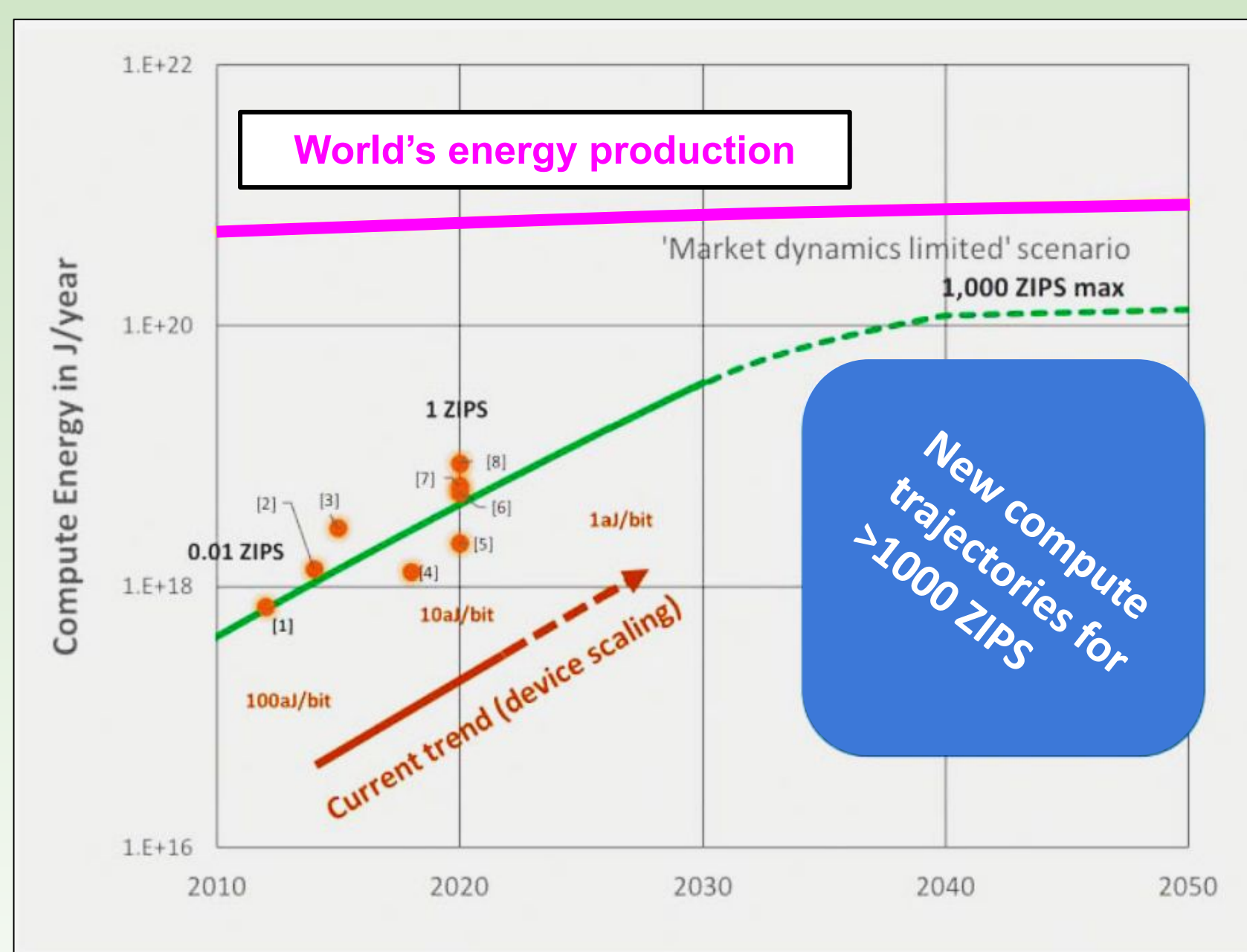
Advanced mathematical strategies to speed up energy-efficient microelectronic device modeling

Nia Maheshwari¹, *Prabhat Kumar², Andy Nonaka²

¹University of Tennessee, Knoxville, ²Lawrence Berkeley National Laboratory

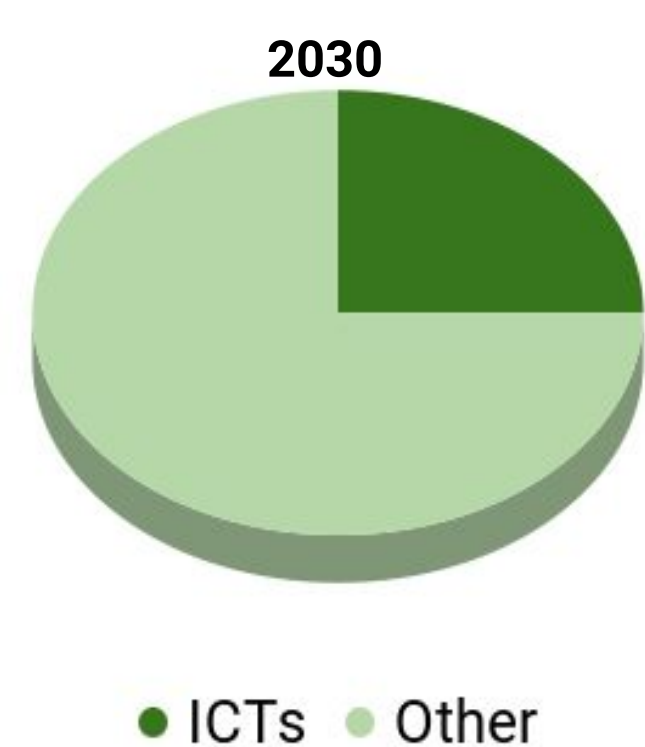
ABSTRACT

Ferroelectric-based transistors can exhibit negative capacitance, a property that allows for lower operating voltages. FerroX is a 3D simulation framework that enables investigation of the energy dynamics within ferroelectric heterostructures. FerroX performs differential-equation based calculations, and is *currently limited by inadequate time integration capabilities*. A successful implementation of the *SUite of Nonlinear and Differential/ALgebraic equation Solvers* (SUNDIALS) support doubled the time step length, and helps overcome this restriction.



Energy inefficiency of computers is the limiting factor in future global computing capacity. Image credit: Semiconductor Research Corporation, Semiconductor Industry Association.

Global Electricity Demand

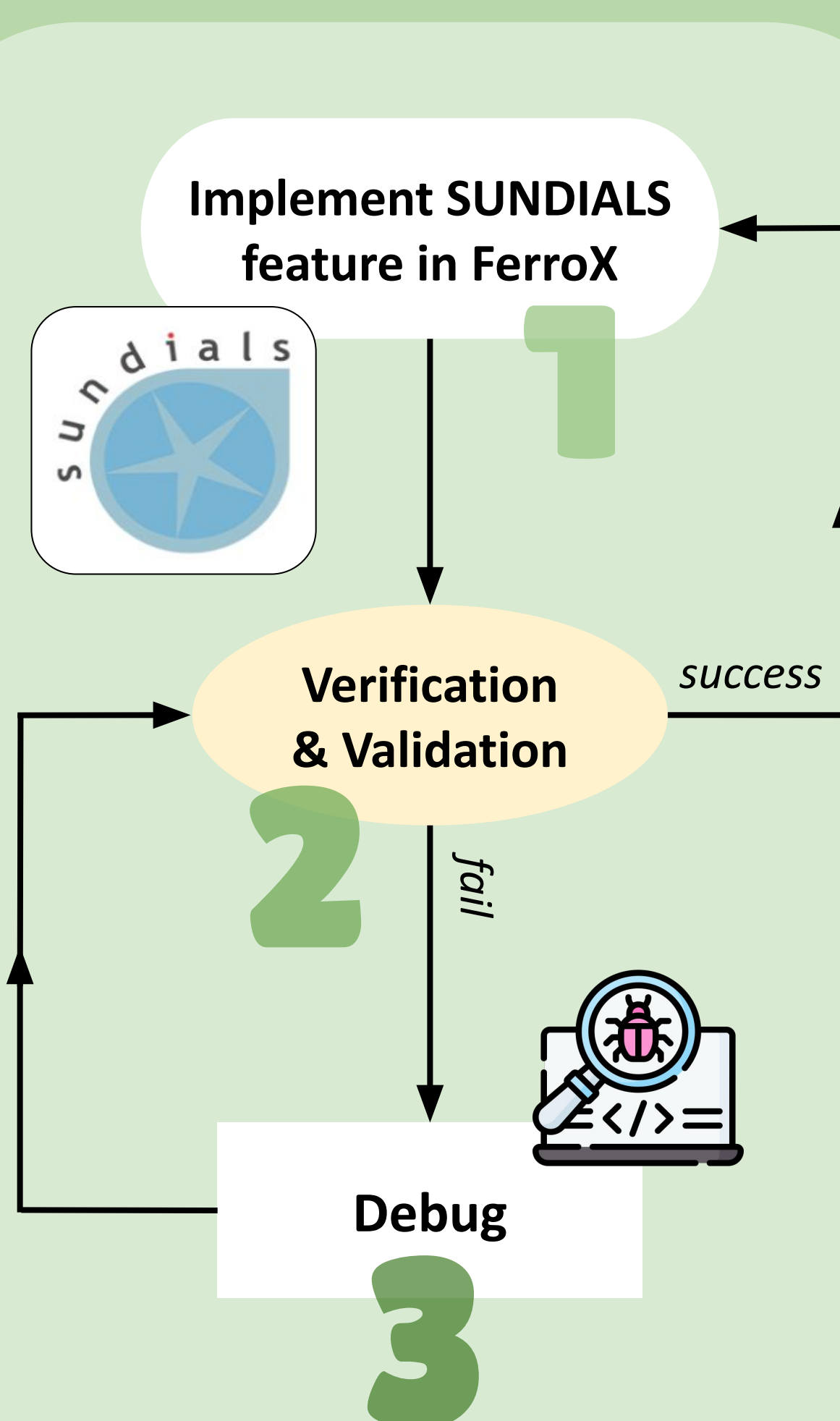


With the current structure of transistors, Information and Communication Technology (ICT) is predicted to account for nearly one quarter of all energy consumption by in 2030.

OUR QUESTION

How can we improve the performance and accuracy of FerroX to simulate ferroelectric-material-based microelectronic devices?

PROCEDURE



EXPLORING ADVANCED METHODS

Diagonally Implicit Runge Kutta (DIRK)	Time step	Runtime
ARKODE_IMPLICIT_TRAPEZOID_2_2	6.0e-13	~700 sec
ARKODE_BILLINGTON_3_3_2	9.0e-13	~630 sec
ARKODE_IMPLICIT_MIDPOINT_1_2	6.0e-13	~600 sec

SUNDIALS offers a different types of time integration methods. The table above shows a few examples of Diagonally Implicit Runge-Kutta (DIRK) methods with their maximum time step. We observe a doubling of the allowable time step.

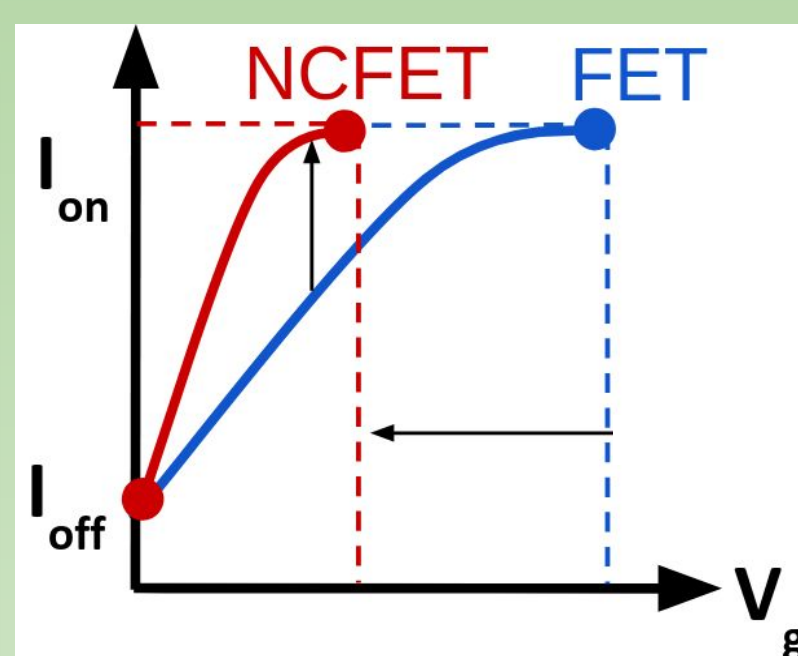
CONCLUSIONS

Time Integration Method	Time step		
	Order	Stable	Unstable
Forward Euler	1	4.0e-13	5.0e-13
Trapezoid	2	4.0e-13	5.0e-13
SSPRK3	3	5.0e-13	6.0e-13
RK4	4	5.0e-13	6.0e-13
ARKODE_BILLINGTON_3_3_2	2	9.0e-13	10.0e-13

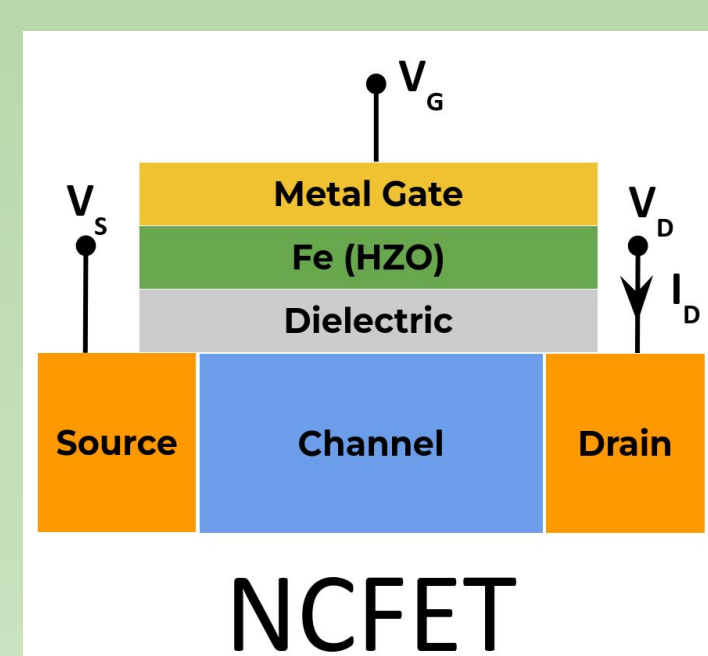
Having validated the SUNDIALS library implementation with convergence tests, we determined the maximum time step supported by several methods.

BACKGROUND

Microelectronic devices function due to the presence of billions of transistors. However, the operating voltage of modern transistors is *unsustainably high*.



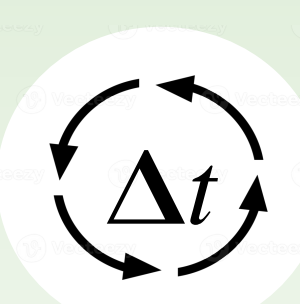
Negative Capacitance Field Effect Transistor (NCFET) requires lower voltage than Field Effect Transistor (FET) to overcome off-on threshold. Image credit: P. Kumar, CSA Postdoc Symposium 2023



Transistor structure shows the gate stack, semiconductor channel, source, and drain. Image credit: Kumar et al. 2024.

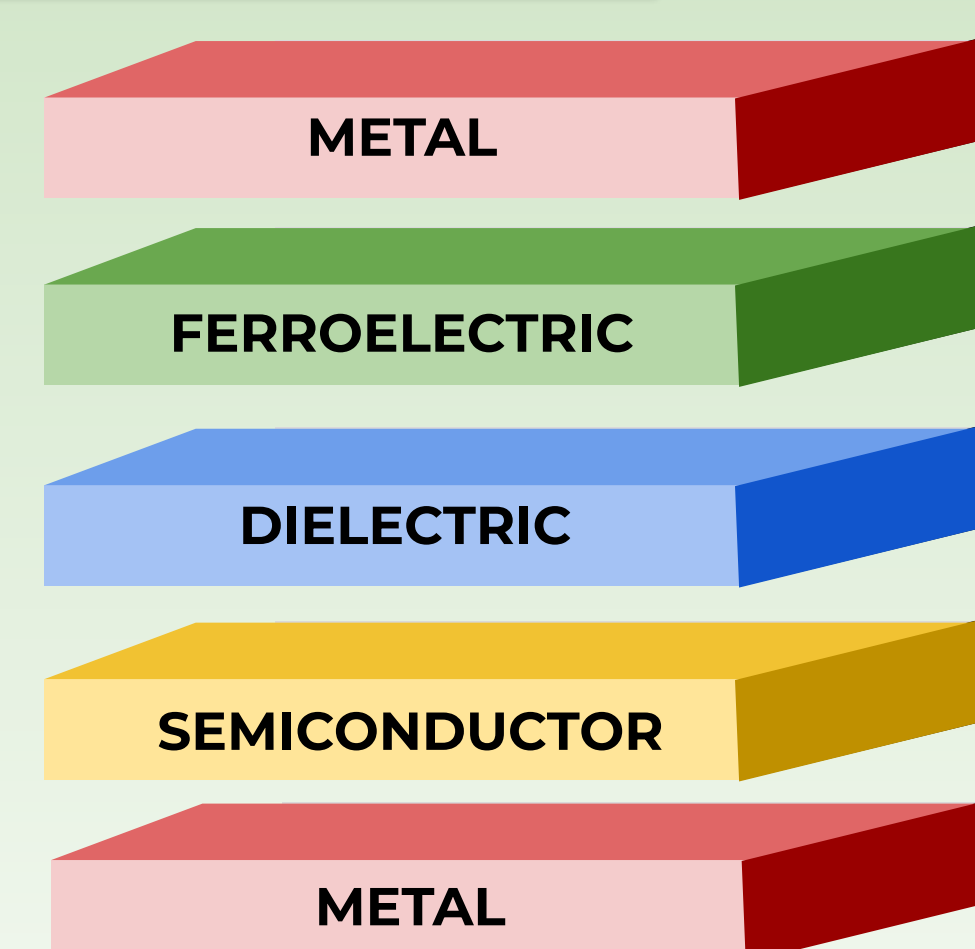
$$\rho(\mathbf{r}) = e[n_p - n_e + N_d^+ - N_a^-]$$

Charge equation for the free charge density of semiconductor



$$\frac{\partial \mathbf{P}(\mathbf{r}, t)}{\partial t} = -\Gamma \frac{\delta F}{\delta \mathbf{P}(\mathbf{r}, t)}$$

Time-Dependent Ginzburg-Landau equation for ferroelectric polarization



The scalable, massively parallel, 3D simulation program FerroX models the complex physical properties of multi-material stacks (illustrated above) by self-consistently solving coupled differential equations (left).

$$\nabla \cdot \epsilon \nabla \Phi = \nabla \cdot \mathbf{P} - \rho$$

Poisson's equation for electric potential

Establishing Baseline FerroX Performance

Internal FerroX Method	Max Supported Timestep	VisIt Output
First Order	4.0e-13	
Second Order	4.0e-13	

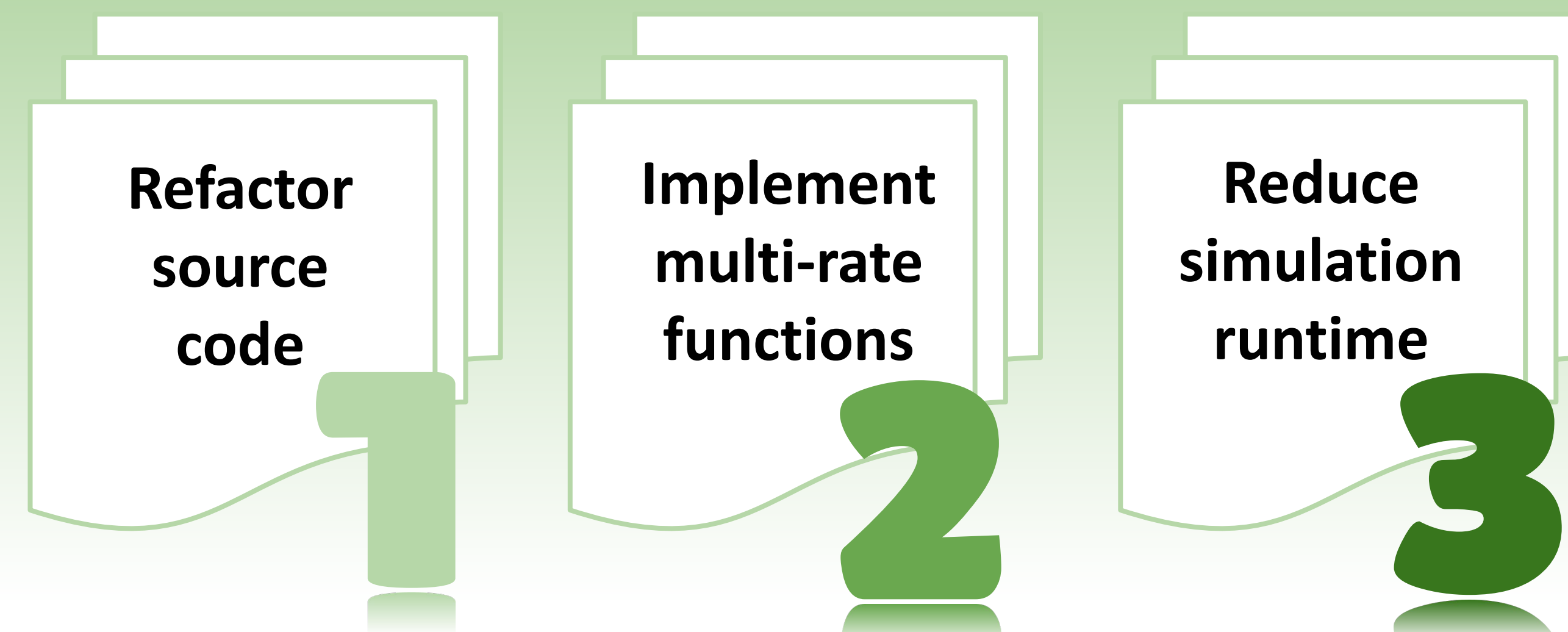
Data from stability testing to determine largest allowable time step length without the support of external math libraries. The right-most column depicts stable simulation output as visualized through the VisIt software.

Verification and Validation of SUNDIALS

Native Runge Kutta	Explicit Runge Kutta (ERK)	Order of Accuracy
Forward Euler	ARKODE_FORWARD_EULER_1_1	1.00
Trapezoid	ARKODE_HEUN_EULER_2_1_2	2.11
SSPRK3	ARKODE_ARK324L2SA_ERK_4_2_3*	3.05
RK4	ARKODE_ARK436L2SA_ERK_6_3_4*	4.07

The convergence rates for SUNDIALS ERK methods correspond to the order of accuracy of each respective Native Runge Kutta method, effectively validating the SUNDIALS implementation.

FUTURE STEPS



ACKNOWLEDGEMENTS

My mentors, Prabhat Kumar and Andy Nonaka, for involving me in their breakthrough research on low-power technology. This work was supported in part by the US Department of Energy, Office of Science, Office of Workforce Development for Teachers and Scientists (WDTS) under the Science Undergraduate Laboratory Internship (SULI) program. **This poster template was inspired by Workforce Development & Education at Berkeley Lab.**



Applied Mathematics & Computational Research

COMPUTING
SCIENCES

THE UNIVERSITY OF
TENNESSEE
KNOXVILLE

Contact: ✉ PrabhatKumar@lbl.gov